

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

CPH3106 — PNP Epitaxial Planar Silicon Transistor DC / DC Converter Applications

Applications

· Relay drivers, lamp drivers, motor drivers, flash

Features

- · Adoption of MBIT processes
- · High current capacitance
- · Low collector-to-emitter saturation voltage
- · High-speed switching
- Ultrasmall package facilitates miniaturization in end products (mounting height: 0.9mm)
- · High allowable power dissipation

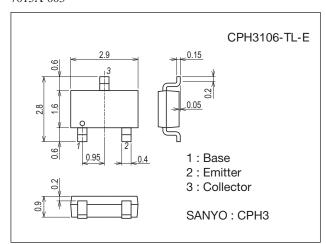
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-15	V
Collector-to-Emitter Voltage	VCEO		-12	V
Emitter-to-Base Voltage	VEBO		-5	V
Collector Current	IC		-3	Α
Collector Current (Pulse)	ICP		-5	Α
Base Current	IB		-600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm)	0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7015A-003



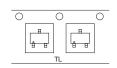
Product & Package Information

• Package : CPH3

• JEITA, JEDEC : SC-59, TO-236, SOT-23

• Minimum Packing Quantity : 3,000 pcs./reel

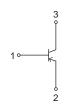
Packing Type: TL



Marking



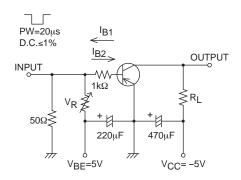
Electrical Connection



Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
		Conditions	min	typ	max	Uill
Collector Cutoff Current	ICBO	V _{CB} = -12V, I _E =0A			-0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} = -4V, I _C =0A			-0.1	μΑ
DC Current Gain	hFE	V _{CE} = -2V, I _C = -500mA	200		560	
Gain-Bandwidth Product	f⊤	V _{CE} = -2V, I _C = -500mA		280		MHz
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		36		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = -1.5A, I _B = -30mA		-110	-165	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = -1.5A, I _B = -30mA		-0.85	-1.2	mV
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C = -10μA, I _E =0A	-15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-12			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE= -10μA, IC=0A	-5			V
Turn-On Time	ton			30		ns
Storage Time	tstg	See specified Test Circuit.		90		ns
Fall Time	tf			10		ns

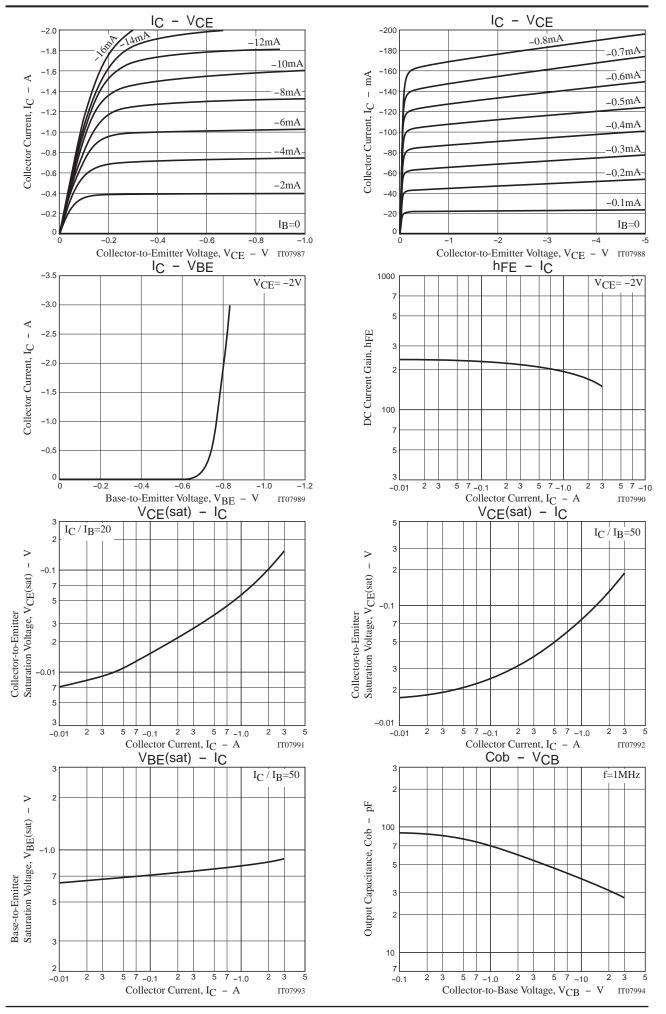
Switching Time Test Circuit

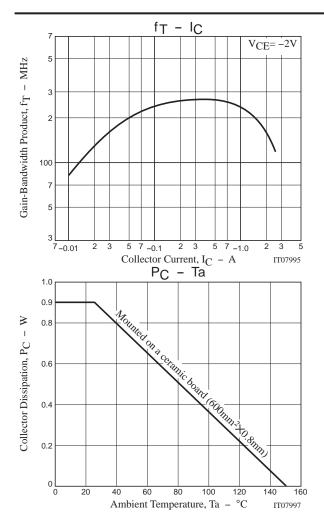


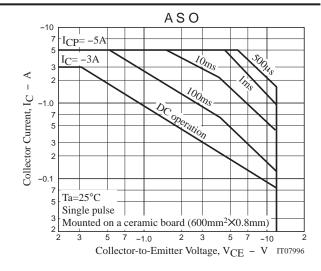
 $-20I_{B1}=20I_{B2}=I_{C}=-1.5A$

Ordering Information

Device	Package	Shipping	memo		
CPH3106-TL-E	CPH3	3,000pcs./reel	Pb Free		





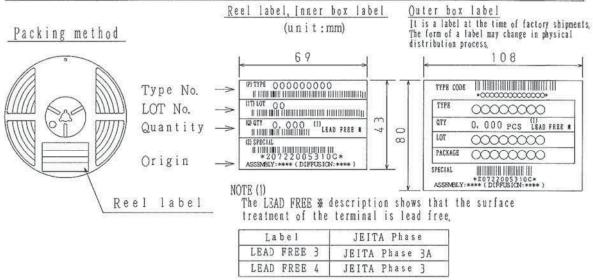


Embossed Taping Specification

CPH3106-TL-E

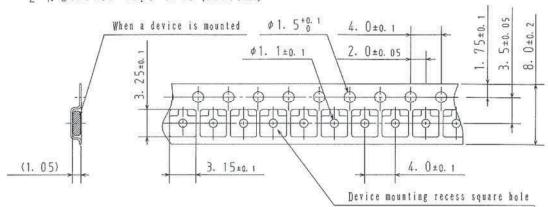
1. Packing Format

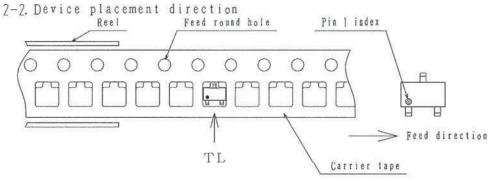
Package Name Carrier Tape Type	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Type	Reel	loner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
СРНЗ	СРНЗ	3, 000	15, 000	90, 000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210	



2. Taping configuration

2-1. Carrier tape size (unit:mm)





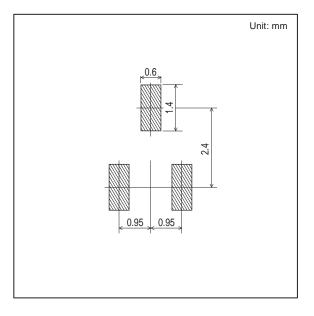
Those with one electrode terminal on the feed hole side TL

Outline Drawing

CPH3106-TL-E

Mass (g) Unit 0.013 *For reference mm 0. 15^{+0. 1}_{-0. 05} 2. 9±0. 1 0.6±0.1 A 0. 2±0. 1 [*1] [*1] 0. 05±0.05 1.6±0.1 [*1] 2 0.6±0.1 0.95 PIN#1 *1:Lot indication

Land Pattern Example



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